

Valence transition behavior of the doped Falicov-Kimball model at nonzero temperatures

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Abstract

The extrapolation of small-cluster exact-diagonalization calculations is used to study the influence of doping on valence transitions in the spinless Falicov-Kimball model at nonzero temperatures. Two types of doping are examined, and namely, the substitution of rare-earth ions by non-magnetic ions that introduce (i) one or (ii) none additional electron (per non-magnetic ion) into the conduction band. It is found that the first type of substitution increases the average f -state occupancy of rare-earth ions, whereas the second type of substitution has the opposite effect. The results obtained are used to describe valence transition behavior of samarium in the hexaboride solid solutions $Sm_{1-x}M_xB_6$ ($M = Y^{3+}, La^{3+}, Sr^{2+}, Yb^{2+}$) and a very good agreement of theoretical and experimental results is found.

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In the past decade, a considerable amount of effort has been devoted to understanding of the multitude of anomalous physical properties of rare-earth and transition-metal compounds. Recent theoretical works based on exact numerical and analytical calculations showed that many of these anomalous features, e.g., mixed valence phenomena, metal-insulator transitions, etc., can be described very well within different versions of the Falicov-Kimball model (FKM) [1, 2, 3]. In particular, it has been found that the spinless FKM, can describe the discontinuous valence and insulator-metal transitions [4, 5] (induced by external pressure) observed experimentally in some rare-earth sulfides, halides and borides [6]. A nice correspondence between theoretical and experimental results has been found, for example, for SmB_6 [5, 7, 8, 9], where the alternative explanation of formation and disappearance of the energy gap in the electronic spectrum of SmB_6 has been presented. For SmB_6 a very good agreement of experimental and theoretical results has been obtained also for nonzero temperatures for both the temperature dependence of the specific heat as well as magnetic susceptibility [10]. In addition, it was found that the spinless FKM can describe the anomalous temperature increase of electrical conductivity σ in SmB_6 (due to the valence transition) [11] as well as the low temperature behavior of σ (due to the appearance of the in-gap structure) in this material [9, 12]. Recently, the FKM has been successfully used to describe the inelastic light scattering in the SmB_6 systems [13]. These results indicate that the spinless FKM is a quite good microscopic model that can describe, at least qualitatively, many of anomalous features of rare-earth compounds. From this point of view it seems to be interesting to ask if this simple model can describe also another kind of experiments performed often in these materials, and namely, the influence of doping on the valence transition behavior of systems. For SmB_6 it has been found, for example [14, 15], that the substitution of Sm by non-magnetic divalent ions (e.g., Sr^{2+}, Yb^{2+}) increases the average samarium valence (the average occupancy of f orbitals decreases), whereas the substitution of Sm by non-magnetic trivalent ions (e.g., Y^{3+}, La^{3+}) produces the opposite effect. In this paper we try to describe the influence of both types of substitutions on the average samarium valence within the spinless FKM.

The spinless FKM is based on the coexistence of two different types of electronic states in given materials: localized, highly correlated ioniclike states and extended,

uncorrelated, Bloch-like states. It is generally accepted that valence and insulator-metal transitions result from a change in the occupation numbers of these electronic states, which remain themselves basically unchanged in their character. The Hamiltonian of the model can be written as the sum of three terms:

$$H = \sum_{ij} t_{ij} d_i^\dagger d_j + U \sum_i f_i^\dagger f_i d_i^\dagger d_i + E_f \sum_i f_i^\dagger f_i, \quad (1)$$

where $f_i^\dagger$, f_i are the creation and annihilation operators for an electron in the localized f state of a rare-earth atom at lattice site i with binding energy E_f and $d_i^\dagger$, d_i are the creation and annihilation operators of the itinerant spinless electrons in the d -band Wannier state at site i . The first term of (1) is the kinetic energy corresponding to quantum-mechanical hopping of the itinerant d electrons between sites i and j . These intersite hopping transitions are described by the matrix elements t_{ij} , which are $-t$ if i and j are the nearest neighbors and zero otherwise (in the following all parameters are measured in units of t). The second term represents the on-site Coulomb interaction between the d -band electrons (with the total number $N_d = \sum_i d_i^\dagger d_i$) and the localized f electrons (with the total number $N_f = \sum_i f_i^\dagger f_i$). The third term stands for the localized f electrons whose sharp energy level is E_f . The Hamiltonian of the FKM doped by divalent (e.g., Sr^{2+}) or trivalent (e.g., Y^{3+}) ions has the same form. From the numerical point of view there is only one difference, and namely, the summation over all lattice sites (in the second and third term) should be replaced by summation over the samarium positions.

Since in the spinless version of the FKM without hybridization the f -electron occupation number $f_i^\dagger f_i$ of each site i commutes with the Hamiltonian (1), the f -electron occupation number is a good quantum number, taking only two values: $w_i = 1$ or 0 , according to whether or not the site i is occupied by the localized f electron. Then the Hamiltonian (1) can be written as

$$H = \sum_{ij} h_{ij} d_i^\dagger d_j + E_f \sum_i w_i, \quad (2)$$

where $h_{ij}(w) = t_{ij} + U w_i \delta_{ij}$.

Thus for a given f -electron configuration $w = \{w_1, w_2 \dots w_L\}$ defined on the one or two-dimensional lattice of L sites with periodic boundary conditions, the

Hamiltonian (2) is the second-quantized version of the single-particle Hamiltonian $h(w) = T + UW$, where T is an L -square matrix with elements t_{ij} and W is the diagonal matrix with elements w_i . The behavior of this model at nonzero temperatures is studied using small-cluster exact-diagonalization calculations. In order to compensate partially for the small size of clusters, thermal properties of the system are investigated via the grand canonical ensemble.

The grand canonical partition function of the FKM [16] can be expressed directly in terms of the eigenvalues ϵ_i of the single-particle operator h , which depend on the f -electron configuration specified by $w = \{w_i\}$, i.e.,

$$\Xi = \sum_w e^{-(E_f - \mu)N_f/\tau} \prod_{i=1}^L [1 + e^{-(\epsilon_i - \mu)/\tau}]. \quad (3)$$

The temperature dependences ($\tau = k_B T$) of the thermodynamic quantities are calculated from this expression by using the standard statistical mechanics procedure. For example, the total number of f -electrons N_f and the internal energy ($\mathcal{E}$) as functions of chemical potential μ are given by [17]

$$N_f(\mu) = -\tau \frac{\partial}{\partial E_f} \ln \Xi, \quad (4)$$

$$\mathcal{E}(\mu) = \frac{1}{L} (\mu\tau \frac{\partial}{\partial \mu} - \frac{\partial}{\partial \beta}) \ln \Xi, \quad (5)$$

where $\beta = 1/\tau$.

In the next, we consider (i) the substitution of rare-earth ions (e.g., Sm) by non-magnetic trivalent ions (e.g., Y^{3+}) which introduce conduction electrons into the d -conduction band (one electron per dopant) and (ii) the substitution of rare-earth ions by non-magnetic divalent ions (e.g., Sr^{2+}) which play a dilution role and reduce the number of conduction electrons in the d -conduction band (no additional electrons are introduced to the system). In the first case the total number of electrons $N = N_f + N_d$ is equal to the total number of lattice sites L (the case of one electron per rare-earth atom is considered) while in the second case $N = L - X$, where X is the total number of dopants. Thus the first step of numerical calculations is to determine the chemical potential corresponding to $N = L$ and $N = L - X$, respectively. Afterwards n_f , $\mathcal{E}$ and other thermodynamic quantities can be calculated

numerically.

It should be noted that the summation over all f electron distributions in (3) should be replaced for the doped FKM by summation over all possible f -electron and dopant distributions, thereby strongly limiting numerical computations. Although the number of configurations can be reduced considerably by the use of symmetries of H , there is still a limit ($L \sim 20$) on the size of clusters that can be studied with this method. However, we will show later that due to small sensitivity of the thermodynamic quantities of the FKM on L , already such small clusters can describe the thermodynamics of the model very well.

To describe effects of doping by divalent and trivalent ions on the average f -state occupancy of rare-earth ions we have performed an exhaustive study of the model for a wide range of model parameters U, τ, E_f . The typical dependences of the average f -orbital occupancy $n_f = N_f/(L - X)$ on the dopant concentration $x = X/L$ are displayed in Fig. 1 for $E_f = 0, U = 0.5$ and several different temperatures τ .

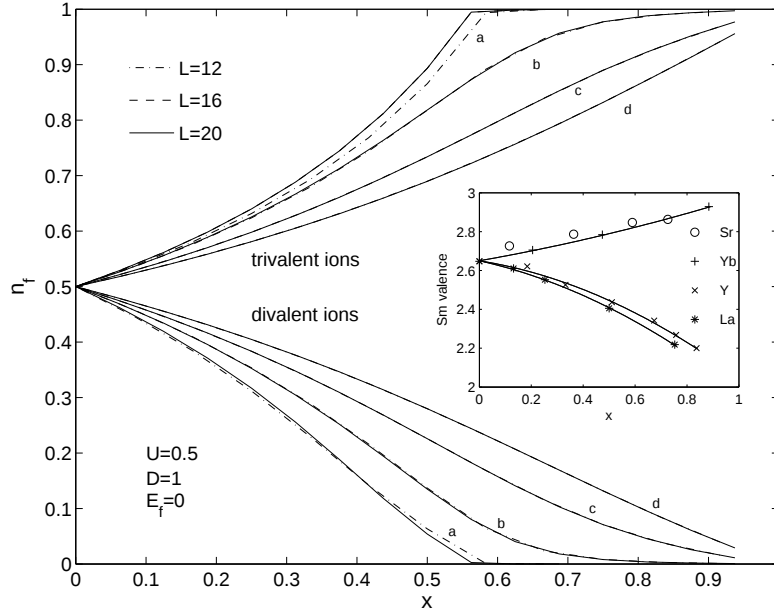


Figure 1: The average occupancy of f orbitals as a function of x for doping by divalent and trivalent ions calculated for $L = 12, 16, 20$ and several different temperatures τ . Curve a , $\tau = 0.1$; curve b , $\tau = 0.3$; curve c , $\tau = 0.6$; curve d , $\tau = 1$. Inset: The average samarium valence in the $Sm_{1-x}M_xB_6$ systems ($M = Y^{3+}, La^{3+}, Sr^{2+}, Yb^{2+}$) measured at 300 K (Ref. 14).

To determine the finite-size effects all concentration dependences have been calculated for several cluster sizes ($L = 12, 16, 20$) and displayed on the common linear scale. We have found that for all examined temperatures τ the finite-size effects are negligible (over the whole range of x plotted) and thus these results can be used satisfactorily to represent the behavior of macroscopic systems. It is seen that the substitution of rare-earth ions by trivalent and divalent ions produces fully different effects. While in the first case the average occupancy of f -orbitals increases with increasing dopant concentration x , in the second case n_f decreases. In all examined cases the valence transition realizes continuously. Comparing these results with experimental measurements of the average samarium valence v (see inset in Fig. 1) in the $Sm_{1-x}M_xB_6$ systems [14, 15] ($M = Y^{3+}, La^{3+}, Sr^{2+}, Yb^{2+}$) one can find a good qualitative agreement between the theoretical and experimental results. Indeed, the substitution of Sm by non-magnetic divalent ions (Sr^{2+}, Yb^{2+}) increases the average samarium valence (the average occupancy of f orbitals $n_f = 3 - v$ decreases), whereas the substitution of Sm by non-magnetic trivalent ions (Y^{3+}, La^{3+}) produces the opposite effect. These results again indicate that the FKM, in spite of its relative simplicity could, in principle, yield the correct physics for describing rare-earth compounds. Even, also small quantitative deviations between the experimental and theoretical results can be straightforwardly improved within the FKM by optimizing the $n_f(x)$ behavior with respect to τ and E_f . This is illustrated in Fig. 2, where the x -dependence of the f -orbital occupancy is plotted for $\tau = 1$ (this relatively large value is chosen to ensure that τ is much greater than the spacing of many-body energy-levels for both $D = 1$ and $D = 2$) and several different values of E_f . It is seen that for nonzero values of E_f a nice correspondence between the theoretical and experimental results can be achieved. Of course, one can take objection that real materials are three dimensional, while our results have been obtained for the one dimensional case. Unfortunately, due to limitations (mentioned above) on the size of clusters that can be treated exactly by small-cluster exact-diagonalization calculations ($L = 20$) we are not able to obtain any exact results in three dimensions. However, in two dimensions there are several finite clusters with $L = 10, 16, 18, 20$ that are accessible to exact-diagonalization calculations [18] and can be used to test the stability of obtained results with increasing dimension. The numerical calculations that we

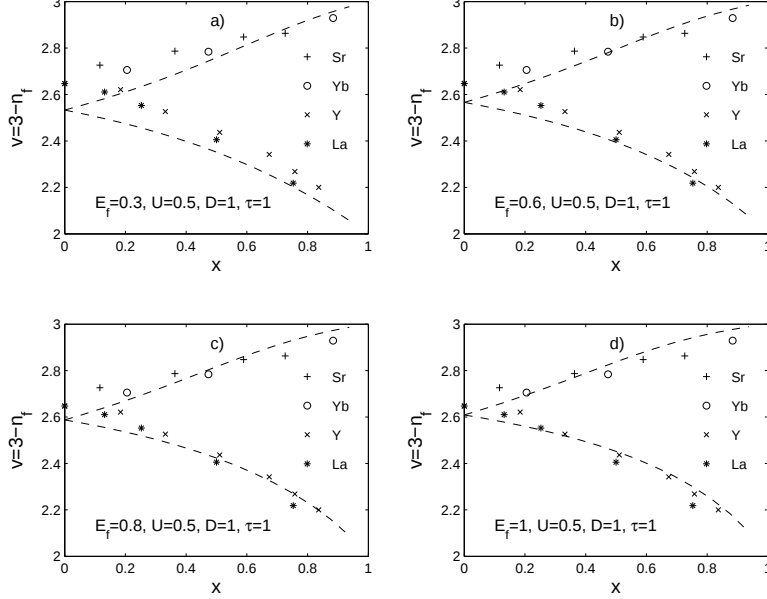


Figure 2: Comparison of the one-dimensional theoretical (dashed lines) and experimental results for the average Sm valence $v = 3 - n_f$ as a function of x . The theoretical results have been calculated for $U = 0.5, \tau = 1$ and several different values of the f -level position E_f . The finite-size effects are negligible, on the linear scale it is not possible on the drawing to distinguish behaviors obtained for $L = 12, 16$ and 20 over the whole range of x plotted. The experimental results have been obtained for $T=300$ K.

have performed in two dimensions (for the same set of model parameters as in $D=1$ and the above mentioned cluster sizes) showed (see Fig. 3) that the f -occupancy of rare-earth orbitals depends only very weakly on the dimension of the system. Thus we can conclude that the spinless FKM, when treated exactly, can provide a reasonable theoretical description of valence transitions induced by doping in some rare-earth compounds, e.g., the samarium hexaboride solid solutions $Sm_{1-x}M_xB_6$ ($M = Y^{3+}, La^{3+}, Sr^{2+}, Yb^{2+}$). Of course, this statement can not be extended automatically on all thermodynamics characteristics of the doped FKM. For example, to do quantitative comparison between the theoretical and experimental results for the specific heat and the magnetic susceptibility, the model should be first generalized by including the spin and orbital dynamics that description was too simplified in the Hamiltonian (1). The work in this direction is currently in progress.

In summary, the extrapolation of small-cluster exact-diagonalization calculations

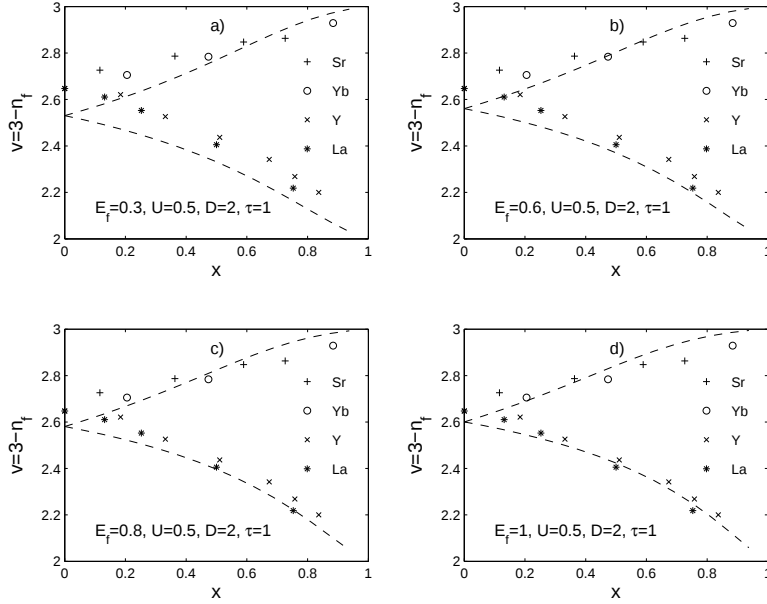


Figure 3: Comparison of the two-dimensional theoretical (dashed lines) and experimental results for the average Sm valence $v = 3 - n_f$ as a function of x . The theoretical results have been obtained on clusters with $L = 10, 16, 20$ for the same set of U, τ and E_f values as in $D = 1$. Again, the finite-size effects are negligible.

was used to study the influence of doping on valence transitions in the spinless FKM at nonzero temperatures. Two types of doping were examined, and namely, the substitution of rare-earth ions by non-magnetic ions that introduce (i) one or (ii) none additional electron (per non-magnetic ion) into the conduction band. It was found that the first type of substitution increases the average f -state occupancy of rare-earth ions, whereas the second type of substitution has the opposite effect. In all examined cases valence changes are continuous. The results obtained were used to describe valence transition behavior of samarium in the hexaboride solid solutions $Sm_{1-x}M_xB_6$ ($M = Y^{3+}, La^{3+}, Sr^{2+}, Yb^{2+}$) and a very good agreement of theoretical and experimental results was found.

Acknowledgments

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